

View Online at <https://aerobasegroup.com/nsn/5961-01-344-0958>

Inclosure Material:

Metal

Mounting Facility Quantity:

2

Component Name And Quantity:

4 transistor

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

500.0 drain to source voltage all transistor

Current Rating Per Characteristic:

164.00 amperes off-state current, peak all transistor and 41.00 amperes drain current all transistor

Power Rating Per Characteristic:

400.0 watts total device dissipation all transistor

Maximum Operating Temperature Per Measurement Point:

150.0 degrees celsius junction

Terminal Type And Quantity:

8 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

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